Ultra Low $V_F = 0.4$ V at $I_F = 5.0$ A

FEATURES

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL J-STD-020. level 1, per LF maximum peak of 260 °C
- AEC-Q101 qualified available: Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

MECHANICAL DATA

Case: SMPD (TO-263AC) Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test Polarity: as marked

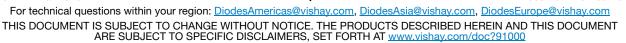
MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V20DM45C	UNIT	
Device marking code			V20DM45C		
Maximum repetitive peak reverse voltage		V _{RRM}	45	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)} ⁽¹⁾	20	Δ	
	per diode		10	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	150	А	
Operating junction temperature range		T _J ⁽²⁾	-40 to +175	- °C	
Storage temperature range		T _{STG}	-55 to +175		

Notes

⁽¹⁾ Mounted on infinite heatsink

 $^{(2)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: dP_D/dT_J < 1/R_{0,JA}

Revision: 14-Mar-2019



DESIGN SUPPORT TOOLS AVAILABLE

Anode 1 O-

Anode 2 O

eSMP[®] Series

SMPD (TO-263AC)

Bottom View

Cathode



2

Top View

PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 10 A			
V _{RRM}	45 V			
I _{FSM}	150 A			
V_F at I_F = 10 A (T_A = 125 °C)	0.46 V			
T _J max.	175 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Common cathode			





RoHS

COMPLIANT

HALOGEN FREE



Vishay General Semiconductor

V20DM45C



www.vishay.com

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F (1)	0.50	-	- V	
	I _F = 10 A			0.54	0.62		
	I _F = 5 A	T _A = 125 °C		0.40	-		
	I _F = 10 A			0.46	0.54		
Reverse current at rated V_R per diode	V _B = 45 V	T _A = 25 °C	I _R ⁽²⁾	-	0.2	mA	
	v _R = 45 v	T _A = 125 °C		3	8		
Typical junction capacitance	4.0 V, 1 MHz		CJ	1460	-	pF	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

 $^{(2)}~$ Pulse test: Pulse width $\leq 5~ms$

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER SYMBOL V2		V20DM45C	UNIT		
Typical thermal resistance per device	$R_{\theta JC}$ ⁽¹⁾	1.8	°C/W		
	R _{0JA} ⁽²⁾⁽³⁾	58			

Notes

⁽¹⁾ Mounted on infinite heatsink

 $^{(2)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$ - junction-to-ambient

⁽³⁾ Free air, without heatsink

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V20DM45C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel		
V20DM45CHM3/I (1)	0.55	l	2000/reel	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified



Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

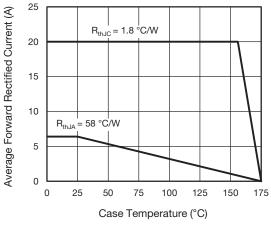


Fig. 1 - Maximum Forward Current Derating Curve

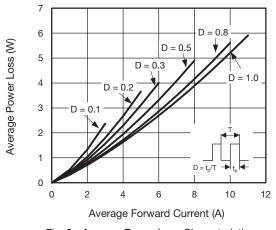
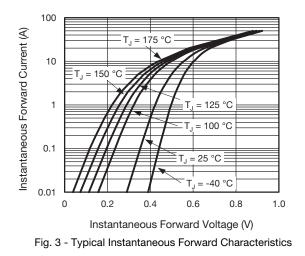


Fig. 2 - Average Power Loss Characteristics



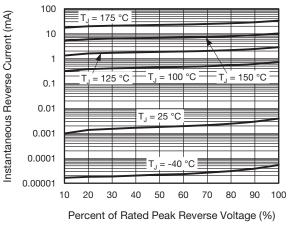
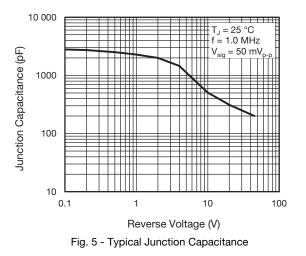


Fig. 4 - Typical Reverse Leakage Characteristics



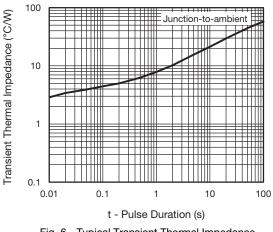


Fig. 6 - Typical Transient Thermal Impedance

Revision: 14-Mar-2019

3

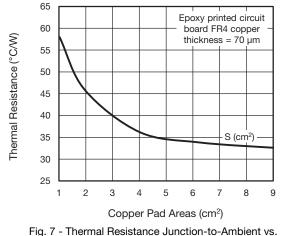
Document Number: 87585

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

V20DM45C

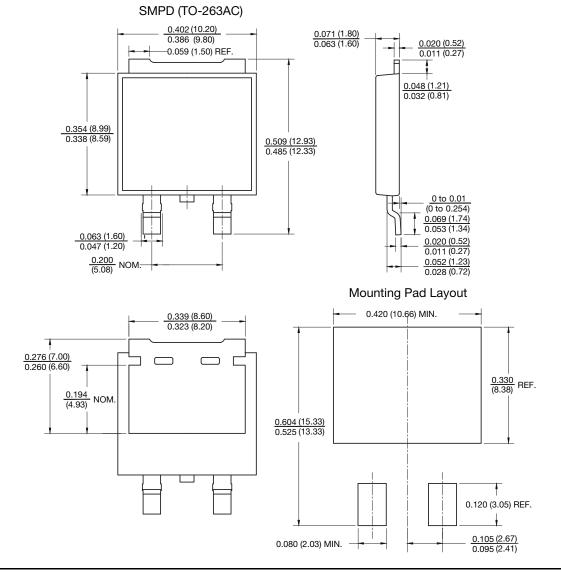


Vishay General Semiconductor



Copper Pad Areas





 Revision: 14-Mar-2019
 Document Number: 87585

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com

 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.